

International  
**IR** Rectifier

**SAFEIR** Series  
8EWS..S

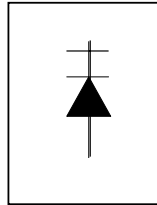
## SURFACE MOUNTABLE INPUT RECTIFIER DIODE

### Description/Features

The 8EWS..S rectifier **SAFEIR** series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150° C junction temperature.

The **High Reverse Voltage** range available allows design of input stage primary rectification with **Outstanding Voltage Surge** capability.

Typical applications are in input rectification and these products are designed to be used with International Rectifier Switches and Output Rectifiers which are available in identical package outlines.



$$V_F < 1V @ 5A$$

$$I_{FSM} = 200A$$

$$V_{RRM} 800 \text{ to } 1200V$$

### Output Current in Typical Applications

Applications	Single-phase Bridge	Three-phase Bridge	Units
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz (140µm) copper	1.2	1.6	A
Aluminum IMS, $R_{thCA} = 15^\circ C/W$	2.5	2.8	
Aluminum IMS with heatsink, $R_{thCA} = 5^\circ C/W$	5.5	6.5	

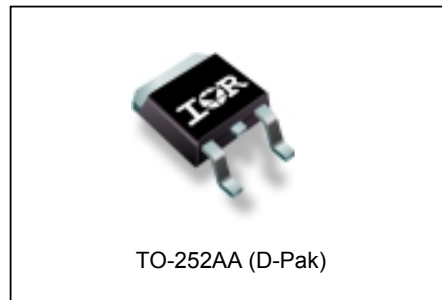
$T_A = 55^\circ C$ ,  $T_J = 125^\circ C$ , footprint 300mm<sup>2</sup>

### Major Ratings and Characteristics

Characteristics	8EWS..S	Units
$I_{F(AV)}$ Sinusoidal waveform	8	A
$V_{RRM}$ Range(*)	800 to 1200	V
$I_{FSM}$	200	A
$V_F$ @ 5A, $T_J = 25^\circ C$	1.0	V
$T_J$	-55 to 150	°C

(\*) for higher voltage up to 1600V contact factory

### Package Outline



## 8EWS..S SAFEIR Series

Bulletin I2108 rev. G 08/00

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### Voltage Ratings

Part Number	$V_{RRM}$ , maximum peak reverse voltage V	$V_{RSM}$ , maximum non repetitive peak reverse voltage V	$I_{RRM}$ 150°C mA
8EWS08S	800	900	0.5
8EWS10S	1000	1100	
8EWS12S	1200	1300	

### Absolute Maximum Ratings

Parameters	8EWS..S	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	8	A	@ $T_c = 95^\circ\text{C}$ , 180° conduction half sine wave
$I_{FSM}$ Max. Peak One Cycle Non-Repetitive Surge Current	170	A	10ms Sine pulse, rated $V_{RRM}$ applied
	200		10ms Sine pulse, no voltage reapplied
$I^2t$ Max. $I^2t$ for fusing	144	$\text{A}^2\text{s}$	10ms Sine pulse, rated $V_{RRM}$ applied
	204		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	2040	$\text{A}^2\sqrt{\text{s}}$	$t = 0.1$ to 10ms, no voltage reapplied

### Electrical Specifications

Parameters	8EWS..S	Units	Conditions
$V_{FM}$ Max. Forward Voltage Drop	1.1	V	@ 8A, $T_J = 25^\circ\text{C}$
$r_t$ Forward slope resistance	21.8	$\text{m}\Omega$	$T_J = 150^\circ\text{C}$
$V_{F(TO)}$ Threshold voltage	0.81	V	
$I_{RM}$ Max. Reverse Leakage Current	0.05	mA	$T_J = 25^\circ\text{C}$
	0.50		$T_J = 150^\circ\text{C}$

$V_R = \text{rated } V_{RRM}$

### Thermal-Mechanical Specifications

Parameters	8EWS..S	Units	Conditions
$T_J$ Max. Junction Temperature Range	-55 to 150	$^\circ\text{C}$	
$T_{stg}$ Max. Storage Temperature Range	-55 to 150	$^\circ\text{C}$	
	Soldering Temperature	240	$^\circ\text{C}$ for 10 seconds (1.6mm from case)
$R_{thJC}$ Max. Thermal Resistance Junction to Case	3	$^\circ\text{C}/\text{W}$	DC operation
$R_{thJA}$ Typ. Thermal Resistance Junction to Ambient (PCB Mount)**	50	$^\circ\text{C}/\text{W}$	
wt Approximate Weight	1(0.03)	g(oz.)	
T Case Style	TO-252AA(D-PAK)		

\*\*When mounted on 1" square (650mm<sup>2</sup>) PCB of FR-4 or G-10 material 4 oz (140µm) copper 40°C/W  
 For recommended footprint and soldering techniques refer to application note #AN-994

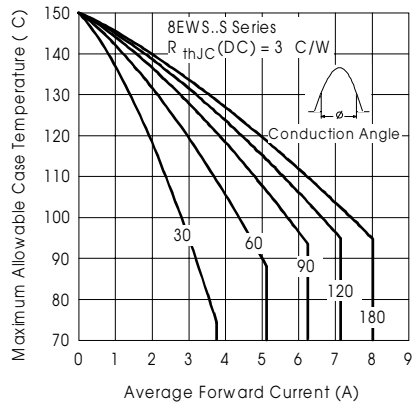


Fig. 1 - Current Rating Characteristics

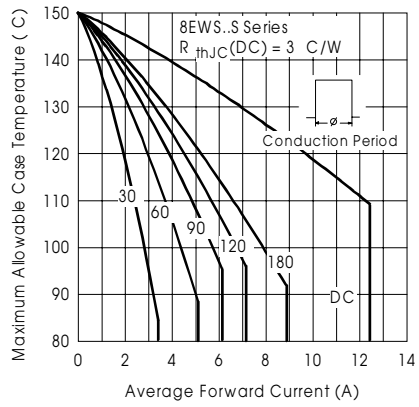


Fig. 2 - Current Rating Characteristics

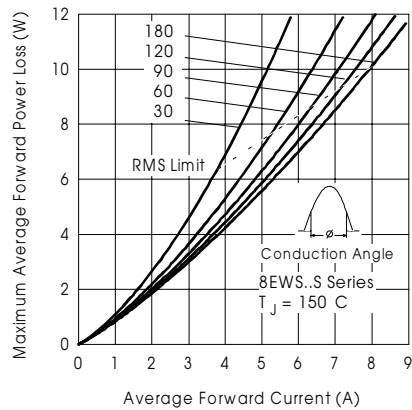


Fig. 3 - Forward Power Loss Characteristics

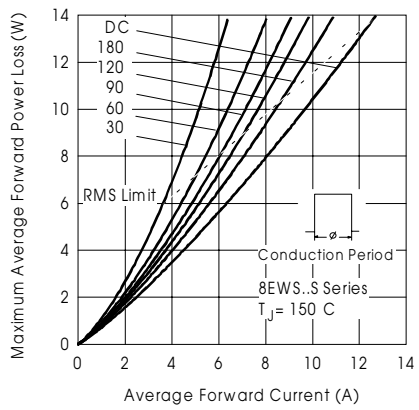


Fig. 4 - Forward Power Loss Characteristics

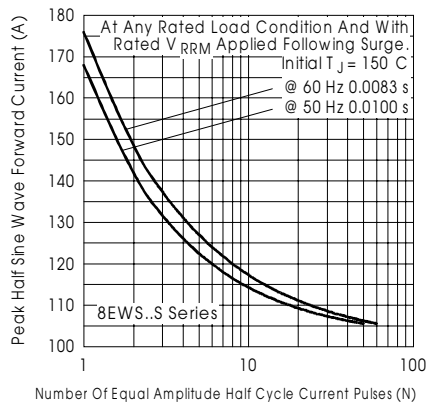


Fig. 5 - Maximum Non-Repetitive Surge Current

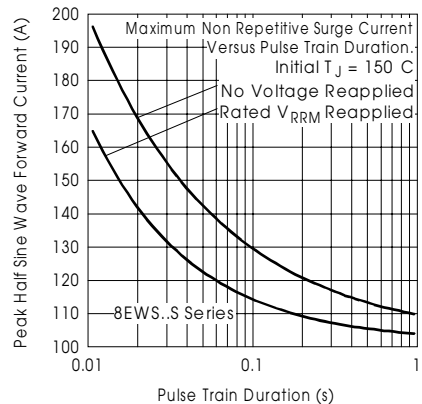


Fig. 6 - Maximum Non-Repetitive Surge Current

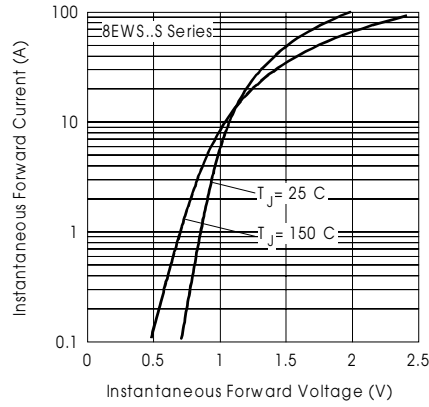


Fig.7-Forward Voltage Drop Characteristics

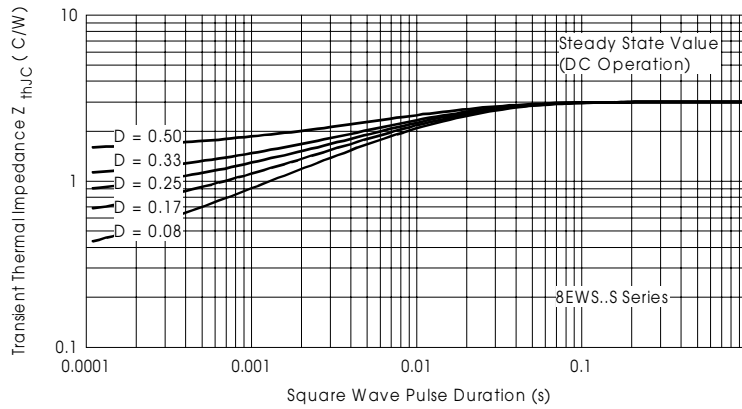


Fig.8-Thermal Impedance  $Z_{thjC}$  Characteristics

Ordering Information Table

**Device Code**

8	E	W	S	12	S	TRL
①	②	③	④	⑤	⑥	⑦

- 1** - Current Rating
- 2** - Circuit Configuration  
E = Single Diode
- 3** - Package  
W = D-PAK
- 4** - Type of Silicon  
S = Standard Recovery Rectifier
- 5** - Voltage code: Code x 100 =  $V_{RRM}$
- 6** - S = Surface Mountable
- 7** - Tape and Reel Option  
TRL = Left Reel  
TRR = Right Orientation Reel

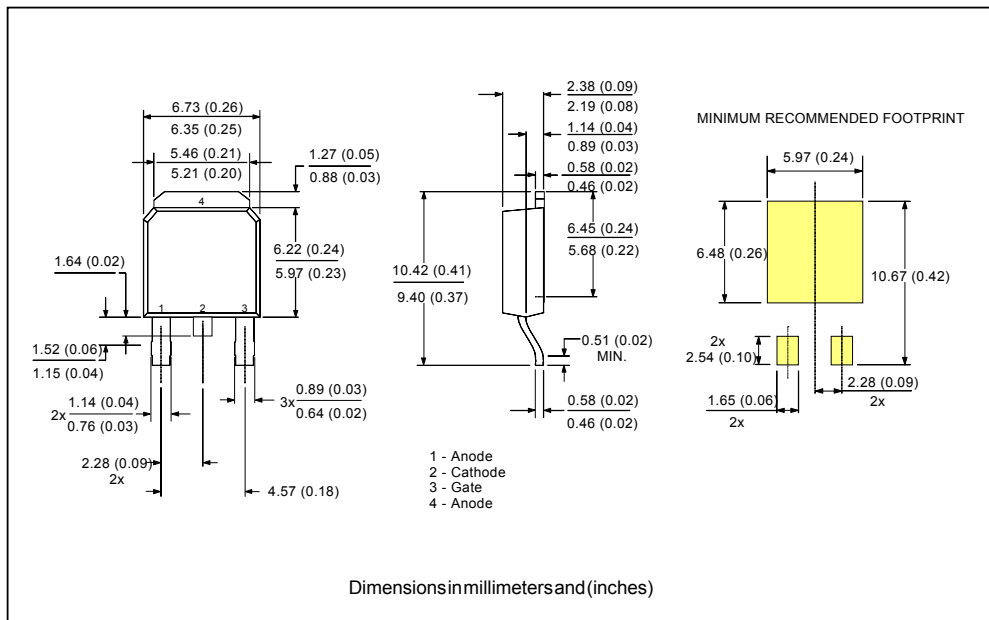
BASE  
CATHODE

ANODE CATHODE ANODE

08 = 800V
10 = 1000V
12 = 1200V

(\*) for higher voltage up to 1600V contact factory

Outline Table

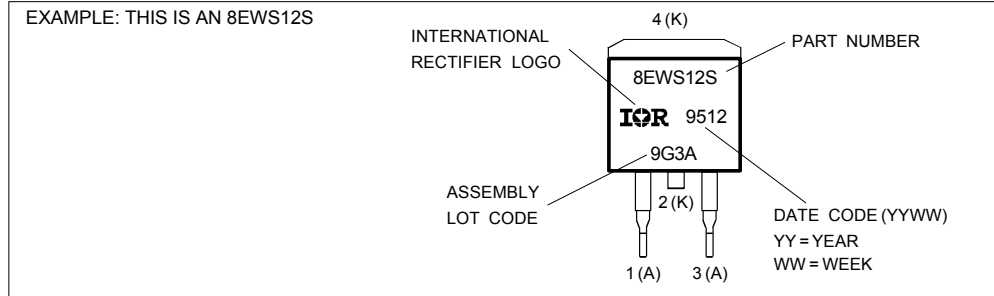


# 8EWS..S *SAFEIR* Series

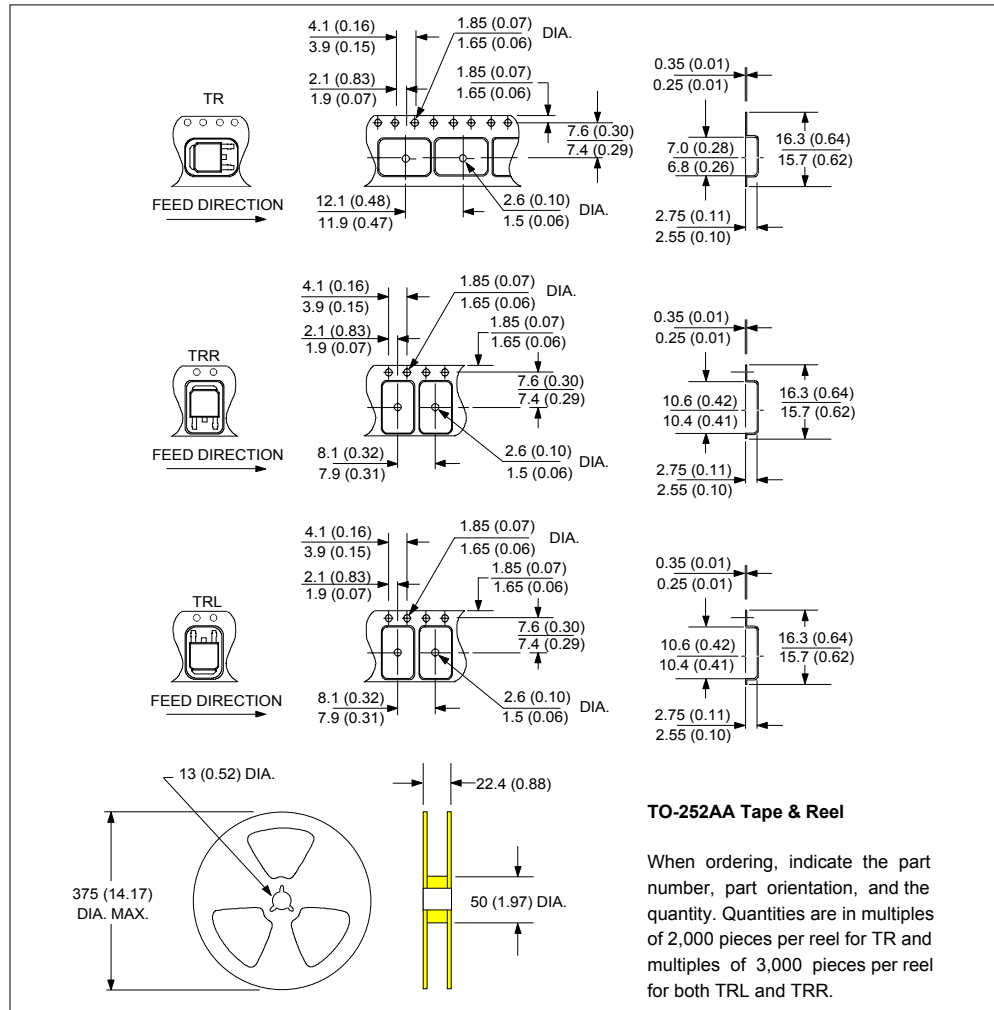
Bulletin I2108 rev. G 08/00

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## Marking Information



## Tape & Reel Information



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**WORLD HEADQUARTERS:** 233 Kansas St., El Segundo, California 90245 U.S.A. Tel: (310) 322 3331. Fax: (310) 322 3332.  
**EUROPEAN HEADQUARTERS:** Hurst Green, Oxted, Surrey RH8 9BB, U.K. Tel: ++ 44 1883 732020. Fax: ++ 44 1883 733408.  
**IR CANADA:** 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801.  
**IR GERMANY:** Saalburgstrasse 157, 61350 Bad Homburg. Tel: ++ 49 6172 96590. Fax: ++ 49 6172 965933.  
**IR ITALY:** Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111. Fax: ++ 39 11 4510220.  
**IR FAR EAST:** K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086.  
**IR SOUTHEAST ASIA:** 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 237994. Tel: ++ 65 838 4630.  
**IR TAIWAN:** 16 Fl. Suite D.207, Sec. 2, Tun Haw South Road, Taipei, 10673, Taiwan. Tel: 886 2 2377 9936.

<http://www.irf.com>

Fax-On-Demand: +44 1883 733420

Data and specifications subject to change without notice.